

Royopto 荣一·光科技

Product Specification

PT4548B-M28-S2

Royopto

5mm Phototransistor PT4548B-M28-S2

PT4548B-M28-S2



Features

- Fast response time
- High photo sensitivity
- 2.54mm Lead spacing
- Pb free
- This product itself will remain within RoHS compliant version.
- Compliance with EU REACH
- Compliance Halogen Free(Br < 900ppm, Cl < 900ppm, Br+Cl < 1500ppm)

Descriptions

- Royopto's PT is a high speed and high sensitive dual phototransistor molded in a black plastic package with flat side view.
- The device is spectrally matched with IR emitters.

Applications

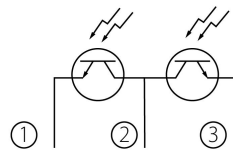
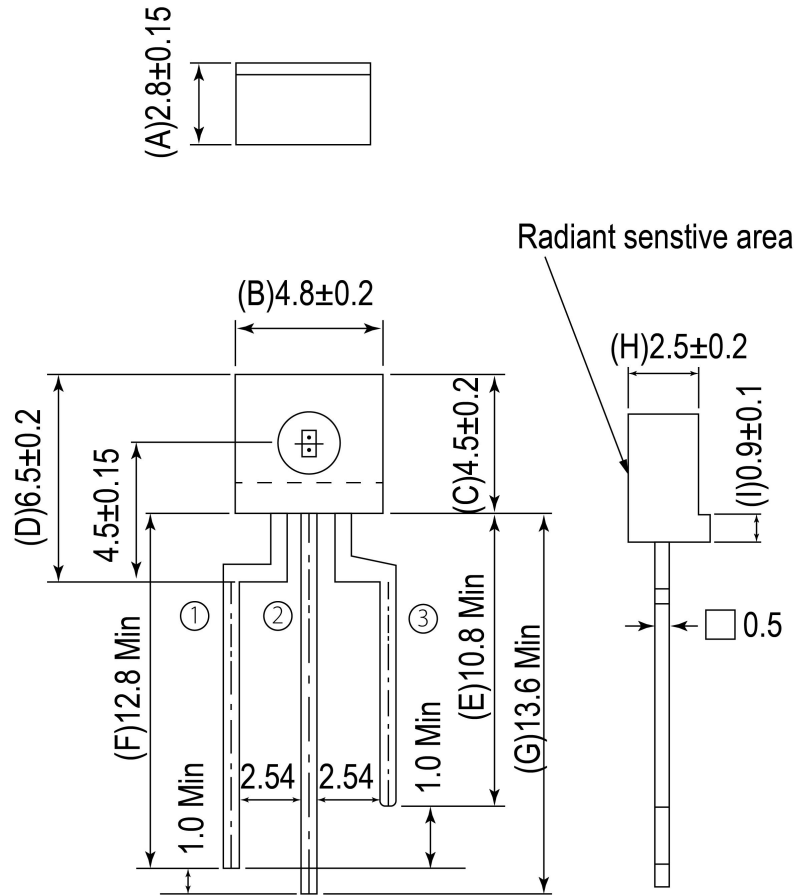
- Infrared applied system
- Mouse
- Optoelectronic Switch
- Photo Interrupter

Device Selection Guide

Device No.	Chip Materials	Lens Color
PT4548B-M28-S2	Silicon	Black

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Package Dimension



- ① Emitter A
- ② Collector
- ③ Emitter B

Note:

1. All dimensions are in millimeters
2. Tolerances unless dimensions ± 0.25 mm

**5mm Phototransistor
PT4548B-M28-S2**
Absolute Maximum Ratings(Ta=25°C)

Parameter	Symbol	Ratings	Unit
Collector-Emitter Voltage	V_{CEO}	30	V
Emitter-Collector-Voltage	V_{ECO}	5	V
Collector Current	I_C	20	mA
Operating Temperature	T_{opr}	-25~ +85	°C
Storage Temperature	T_{stg}	-40 ~ +100	°C
Lead Soldering Temperature (*1)	T_{sol}	260	°C
Power Dissipation at (or below) 25°C Free Air Temperature	P_C	75	mW

Notes:

1. Soldering time \leq 5 seconds

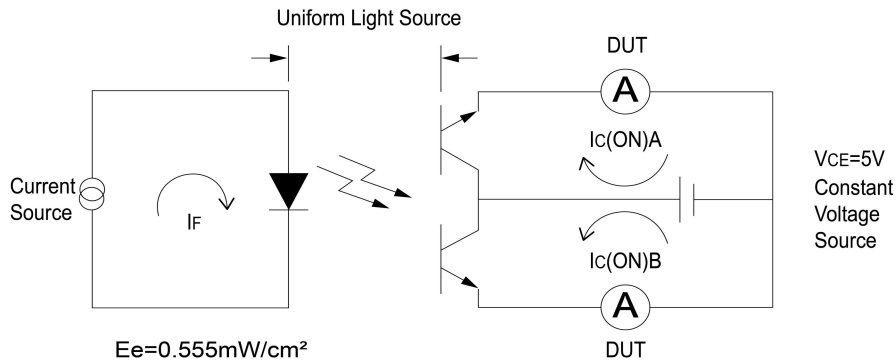
Electro-Optical Characteristics(Ta=25°C)

Paramete	Symbol	Condition	Min.	Typ.	Max.	Units
Collector – Emitter Breakdown Voltage	BV_{CEO}	$I_C=100\mu A$ $E_e=0mW/cm^2$	30	--	--	V
Emitter-Collector Breakdown Voltage	BV_{ECO}	$I_E=100\mu A$ $E_e=0mW/cm^2$	5	--	--	V
Collector-Emitter Saturation Voltage	$V_{CE(sat)}$	$I_C=2mA$ $E_e=1mW/cm^2$	--	--	0.4	V
Rise Time	t_r	$V_{CE}=5V$ $I_C=1mA$	--	15	--	μS
Fall Time	t_f	$RL=1000\Omega$	--	15	--	
Collector Dark Current	I_{CEO}	$E_e=0mW/cm^2$ $V_{CE}=20V$	--	--	100	nA
On State Collector Current	$I_{C(on)}$	$E_e=1mW/cm^2$ $V_{CE}=5V$	129	--	1085	mA
Wavelength of Peak Sensitivity	λ_p	--	--	940	--	nm
Rang of Spectral Bandwidth	$\lambda_{0.5}$	--	760	--	1100	nm

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Test Method For On State Collector Current

Condition : $E_e=0.555\text{mW/cm}^2$, $V_{CE}=5\text{V}$ Test Item : Collector Current [$I_{C(ON)}$] Unit : μA



Rank

Ranks	Symbol	Min	Typ	Max	Unit	Test Condition
A1	$I_{C(ON)}$	129	--	226	μA	$E_e=0.555\text{mW/cm}^2$ $V_{CE}=5\text{V}$
A2	$I_{C(ON)}$	195	--	306	μA	$E_e=0.555\text{mW/cm}^2$ $V_{CE}=5\text{V}$
A3	$I_{C(ON)}$	262	--	380	μA	$E_e=0.555\text{mW/cm}^2$ $V_{CE}=5\text{V}$
A4	$I_{C(ON)}$	330	--	461	μA	$E_e=0.555\text{mW/cm}^2$ $V_{CE}=5\text{V}$
A5	$I_{C(ON)}$	398	--	544	μA	$E_e=0.555\text{mW/cm}^2$ $V_{CE}=5\text{V}$
A6	$I_{C(ON)}$	468	--	625	μA	$E_e=0.555\text{mW/cm}^2$ $V_{CE}=5\text{V}$
A7	$I_{C(ON)}$	536	--	703	μA	$E_e=0.555\text{mW/cm}^2$ $V_{CE}=5\text{V}$
A8	$I_{C(ON)}$	604	--	785	μA	$E_e=0.555\text{mW/cm}^2$ $V_{CE}=5\text{V}$
A9	$I_{C(ON)}$	673	--	862	μA	$E_e=0.555\text{mW/cm}^2$ $V_{CE}=5\text{V}$
A10	$I_{C(ON)}$	742	--	944	μA	$E_e=0.555\text{mW/cm}^2$ $V_{CE}=5\text{V}$
A11	$I_{C(ON)}$	812	--	1018	μA	$E_e=0.555\text{mW/cm}^2$ $V_{CE}=5\text{V}$
A12	$I_{C(ON)}$	882	--	1085	μA	$E_e=0.555\text{mW/cm}^2$ $V_{CE}=5\text{V}$

Note:

1. Measurement Uncertainty of Forward Voltage: $\pm 0.1\text{V}$
2. Measurement Uncertainty of Luminous Intensity: $\pm 10\%$
3. Measurement Uncertainty of Dominant Wavelength $\pm 1.0\text{nm}$

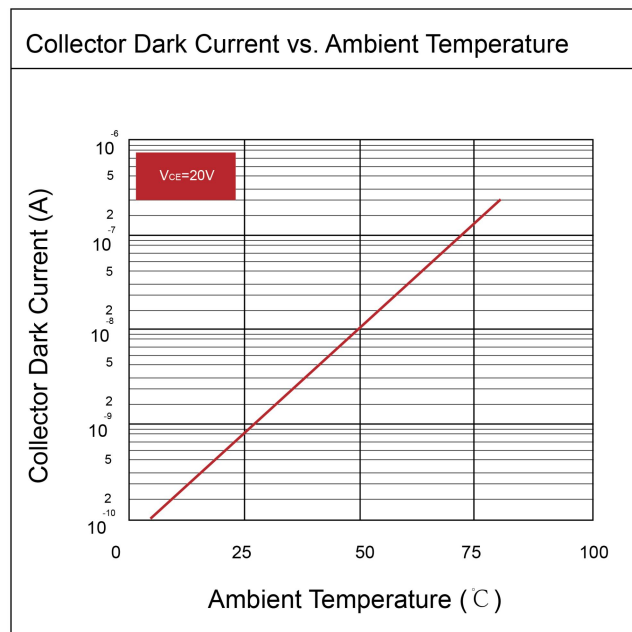
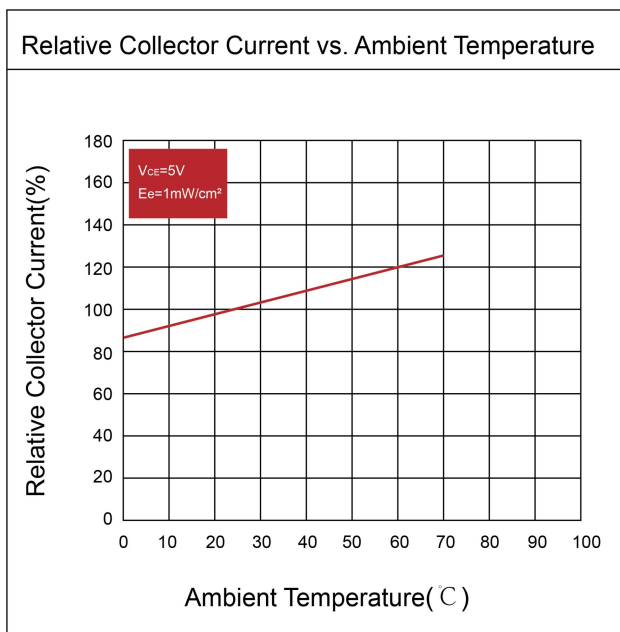
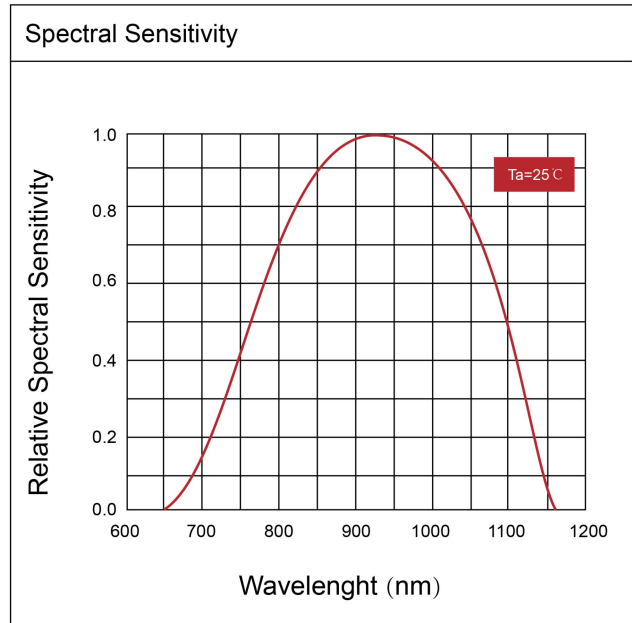
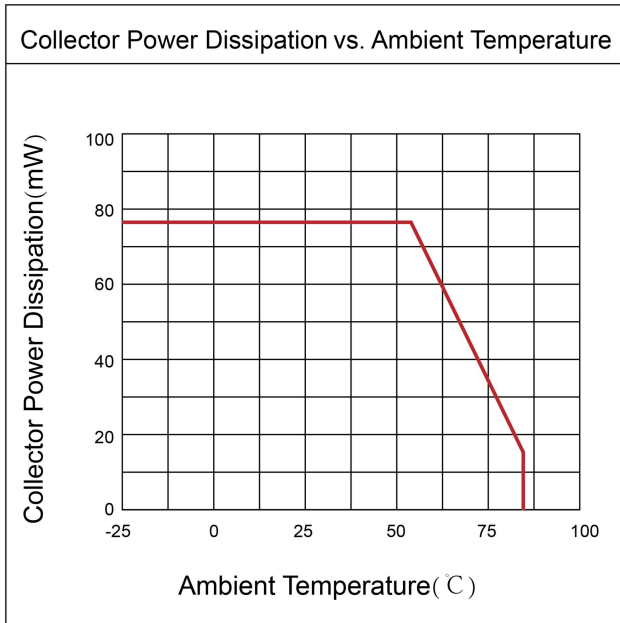
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Reliability Test Item And Condition

- The reliability of products shall be satisfied with items listed below.
- Confidence level: 90% LTPD: 10%

NO.	Item	Test Conditions	Test Conditions	Sample Sizes	Failure Judgement Criteria	Ac/Re
1	Solder Heat	TEMP.: 260°C±5°C	10secs	22pcs	Attenuation of Power brightness or Electrical value>20%	0/1
2	Temperature Cycle	H : +100°C 30mins ↕ 5mins L : -40°C 30mins	300Cycles	22pcs		0/1
3	Thermal Shock	H :+100°C 5mins ↕ 10secs L :-10°C 5mins	300Cycles	22pcs		0/1
4	High Temperature Storage	TEMP: +100°C	1000hrs	22pcs		0/1
5	Low Temperature Storage	TEMP: -40°C	1000hrs	22pcs		0/1
6	DC Operating Life	I _F =20mA	1000hrs	22pcs		0/1
7	High Temperature/ High Humidity	85°C / 85% R.H	1000hrs	22pcs		0/1

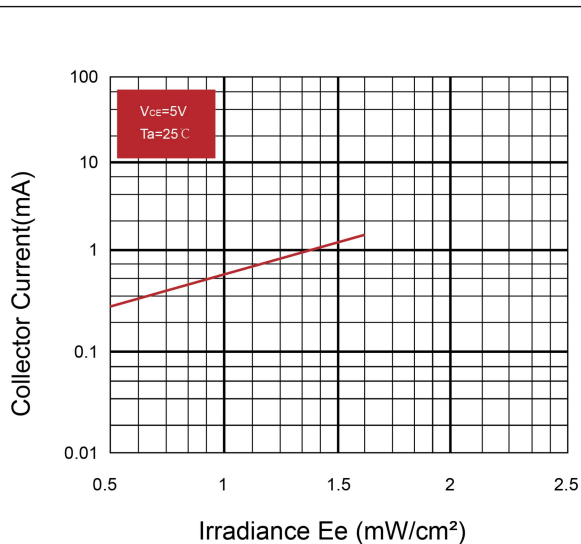
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Typical Electrical/Optical/Characteristics Curves

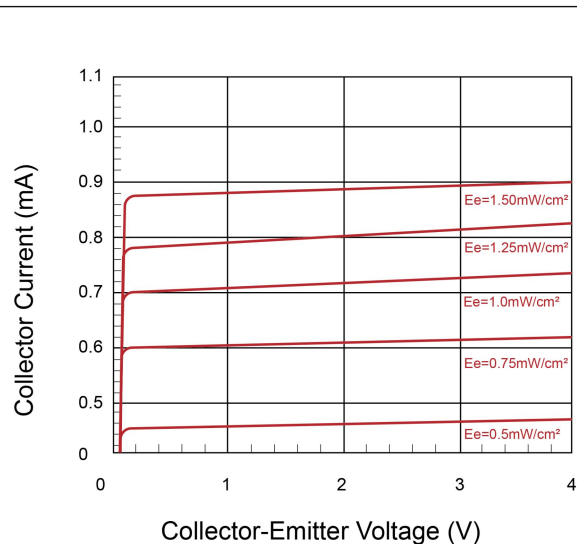


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Collector Current vs. Irradiance

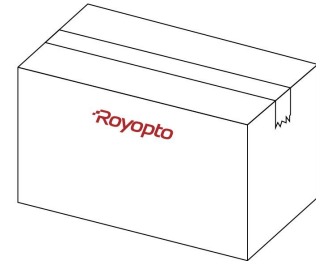
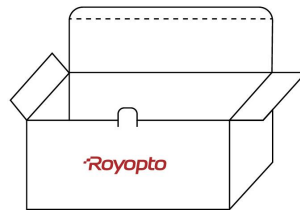


Collector Current vs. Collector-Emitter Voltage



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Package Dimensions



Anti-electrostatic bag

Inner Bag

Outside Carton

Size: 210*160mm

215*145*96mm

535*318*240mm

Packing: 1000pcs/Bag

6Bags/Box

10Boxes/Carton

Label Form Specification

- CPN: Customer's Product Number
- MAT: Product Number
- QTY: Packing Quantity
- CAT: Luminous Intensity Rank
- HUE: Dom. Wavelength Rank
- REF: Forward Voltage Rank
- LOTNO: Lot Number
- DC: Date Created
- SERNO: Identify Label Number



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Notes

1. Lead Forming

- During lead formation, the leads should be bent at a point at least 3mm from the base of the epoxy bulb.
- Lead forming should be done before soldering.
- Avoid stressing the LED package during leads forming. The stress to the base may damage the LED's characteristics or it may break the LEDs.
- Cut the LED lead frames at room temperature. Cutting the lead frames at high temperatures may cause failure of the LEDs.
- When mounting the LEDs onto a PCB, the PCB holes must be aligned exactly with the lead position of the LED. If the LEDs are mounted with stress at the leads, it causes deterioration of the epoxy resin and this will degrade the LEDs.

2. Storage

- The LEDs should be stored at 30°C or less and 70%RH or less after being shipped from Royopto and the storage life limits are 3 months. If the LEDs are stored for 3 months or more, they can be stored for a year in a sealed container with a nitrogen atmosphere and moisture absorbent material.
- Please avoid rapid transitions in ambient temperature, especially, in high humidity environments where condensation can occur.

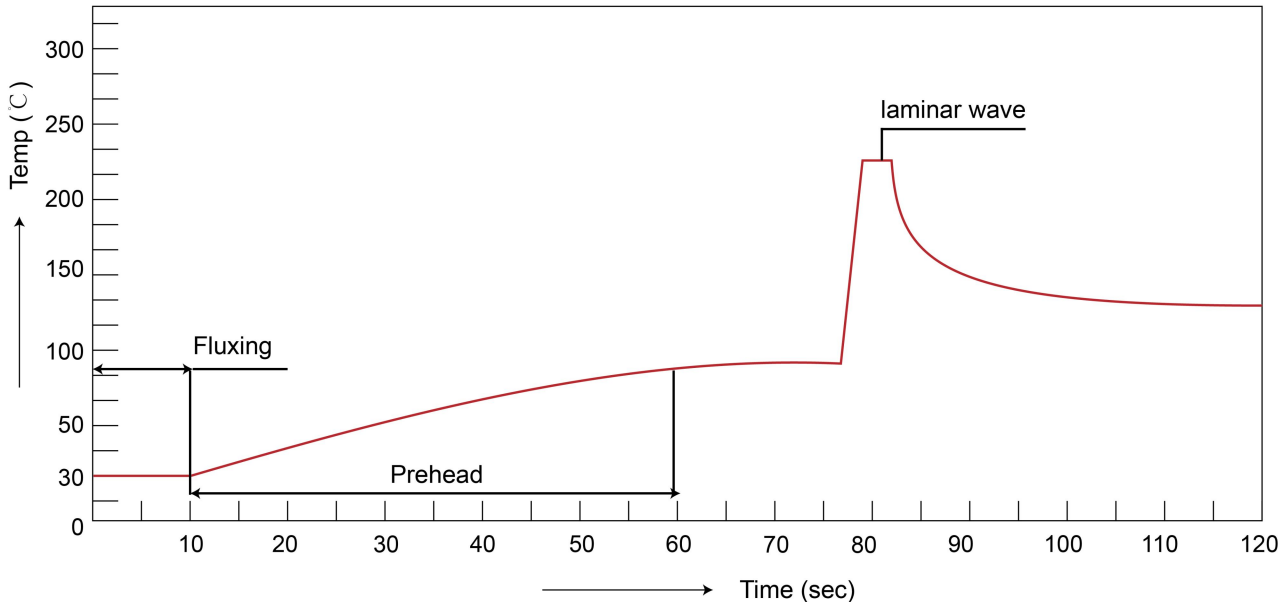
3. Soldering

- Careful attention should be paid during soldering. When soldering, leave more than 3mm from solder joint to epoxy bulb, and soldering beyond the base of the tie bar is recommended.
- Recommended soldering conditions:

Hand Soldering		DIP Soldering	
Temp. at tip of iron	300°C Max. (30W Max.)	Preheat temp.	100°C Max. (60 sec Max.)
Soldering time	3 sec Max.	Bath temp. & time	260 Max., 5 sec Max
Distance	3mm Min.(From solder joint to epoxy bulb)	Distance	3mm Min. (From solder joint to epoxy bulb)

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■ Recommended soldering profile



- Avoiding applying any stress to the lead frame while the LEDs are at high temperature particularly when soldering.
- Dip and hand soldering should not be done more than one time.
- After soldering the LEDs, the epoxy bulb should be protected from mechanical shock or vibration until the LEDs return to room temperature.
- A rapid-rate process is not recommended for cooling the LEDs down from the peak temperature. Although the recommended soldering conditions are specified in the above table, dip or hand soldering at the lowest possible temperature is desirable for the LEDs.
- Wave soldering parameter must be set and maintain according to recommended temperature and dwell time in the solder wave.

4. Cleaning

- When necessary, cleaning should occur only with isopropyl alcohol at room temperature for a duration of no more than one minute. Dry at room temperature before use.
- Do not clean the LEDs by the ultrasonic. When it is absolutely necessary, the influence of ultrasonic cleaning on the LEDs depends on factors such as ultrasonic power and the assembled condition. Ultrasonic cleaning shall be pre-qualified to ensure this will not cause damage to the LED.

5. Heat Management

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- Heat management of LEDs must be taken into consideration during the design stage of LED application. The current should be de-rated appropriately by referring to the de-rating curve found in each product specification.
- The temperature surrounding the LED in the application should be controlled. Please refer to the data sheet de-rating curve.

6. ESD (Electrostatic Discharge)

- Electrostatic discharge (ESD) or surge current (EOS) can damage LEDs.
- An ESD wrist strap, ESD shoe strap or antistatic gloves must be worn whenever handling LEDs.
- All devices, equipment and machinery must be properly grounded.
- Use ion blower to neutralize the static charge which might have built up on surface of the LEDs plastic lens as a result of friction between LEDs during storage and handing.

7. Other

- Above specification may be changed without notice. Royopto will reserve authority on material change for above specification.
- When using this product, please observe the absolute maximum ratings and the instructions for using outlined in these specification sheets. Royopto assumes no responsibility for any damage resulting from use of the product which does not comply with the absolute maximum ratings and the instructions included in these specification sheets.
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